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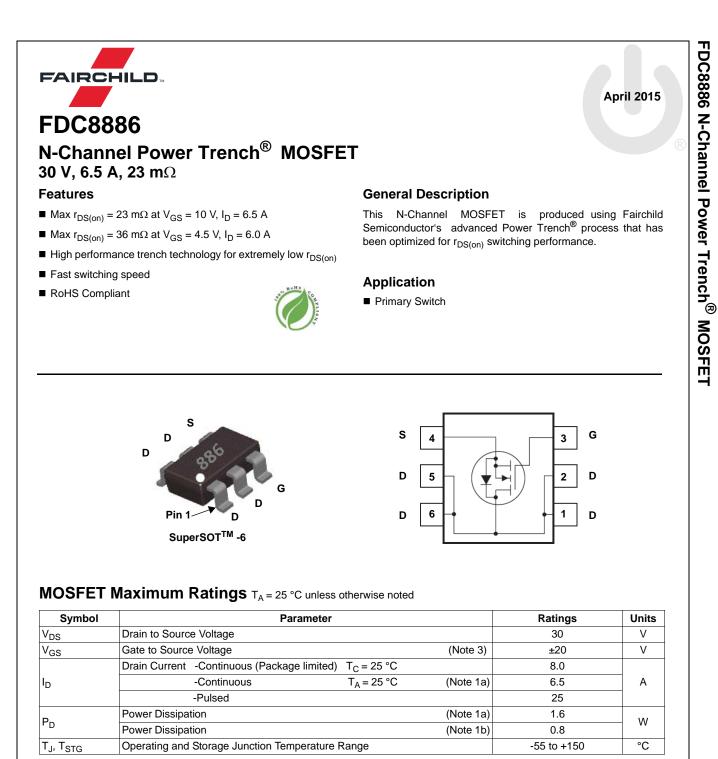


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	30	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 78	C/W

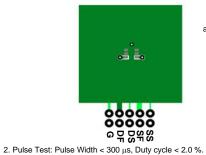
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.886	FDC8886	SSOT-6	7 "	8 mm	3000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		18		mV/°C	
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA	
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA	
On Chara	acteristics	· · · · · ·					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.2	1.9	3.0	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 6.5 A		19	23	mΩ	
		$V_{GS} = 4.5 \text{ V}, I_D = 6.0 \text{ A}$		30	36		
		V _{GS} = 10 V, I _D = 6.5 A, T _J = 125 °C		25	30		
9 FS	Forward Transconductance	$V_{DD} = 5 \text{ V}, I_D = 6.5 \text{ A}$		24		S	
C _{iss} C _{oss} C _{rss}	Input Capacitance Output Capacitance Reverse Transfer Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		348 135 16	465 180 25	pF pF pF	
R _q	Gate Resistance			1.2	20	Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time	-		5	10	ns	
t _r	Rise Time	$V_{DD} = 15 \text{ V}, \text{ I}_{D} = 6.5 \text{ A},$		1	10	ns	
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		11	19	ns	
t _f	Fall Time			1	10 7.4	ns	
-1	Tatal Cata Channe			5.3	7.4	nC	
	Total Gate Charge	$V_{GS} = 0 \text{ V to } 10 \text{ V}$		0 E	2 5		
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V} \text{ V}_{DD} = 15 \text{ V}$		2.5	3.5	nC	
Q _{g(TOT)} Q _{gs}	Total Gate Charge Total Gate Charge			1.0	3.5	nC	
Q _{g(TOT)} Q _{gs} Q _{gd}	Total Gate ChargeTotal Gate ChargeGate to Drain "Miller" Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V} \text{ V}_{DD} = 15 \text{ V}$		-	3.5	-	
Q _{g(TOT)} Q _{gs} Q _{gd} Drain-So	Total Gate Charge Total Gate Charge Gate to Drain "Miller" Charge urce Diode Characteristics	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 15 \text{ V}$ $I_D = 6.5 \text{ A}$		1.0 0.8		nC nC	
Q _{g(TOT)} Q _{gs} Q _{gd}	Total Gate Charge Total Gate Charge Gate to Drain "Miller" Charge urce Diode Characteristics Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V to } 4.5 \text{ V} \text{ V}_{DD} = 15 \text{ V}$		1.0 0.8 0.86	1.2	nC	
Q _{g(TOT)} Q _{gs} Q _{gd} Drain-So	Total Gate Charge Total Gate Charge Gate to Drain "Miller" Charge urce Diode Characteristics	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 15 \text{ V}$ $I_D = 6.5 \text{ A}$		1.0 0.8		nC nC	

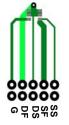
Q_{rr} NOTES:

 $R_{0,C}$ is guaranteed by design while R_{0CA} is determined by the user's board design.



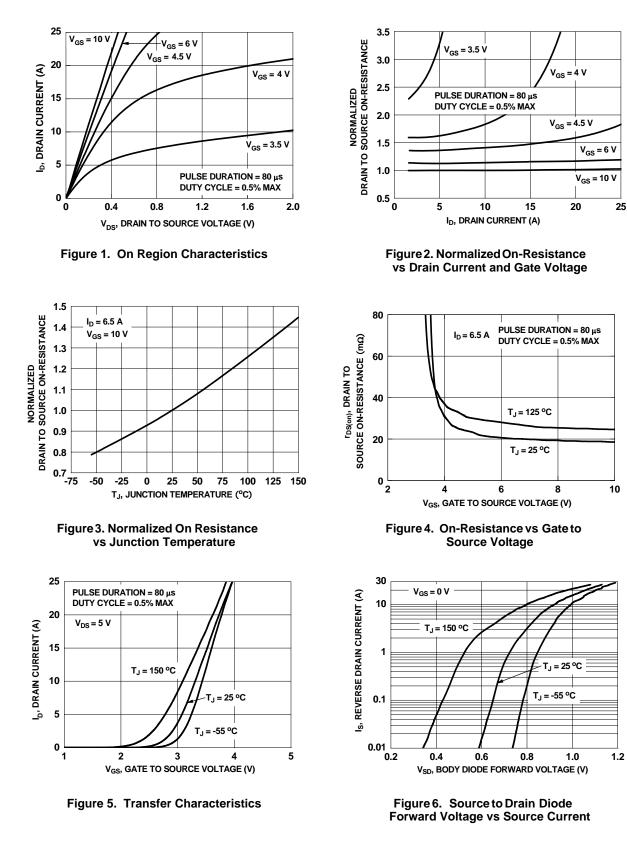
a. 78 °C/W when mounted on a 1 in² pad of 2 oz copper

3. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.



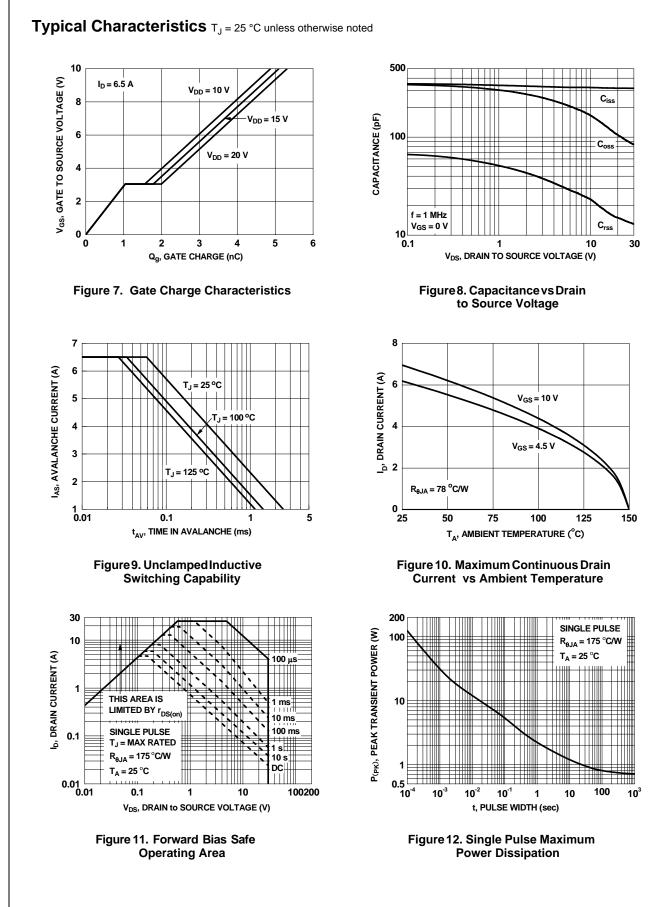
b.175 °C/W when mounted on a minimum pad of 2 oz copper

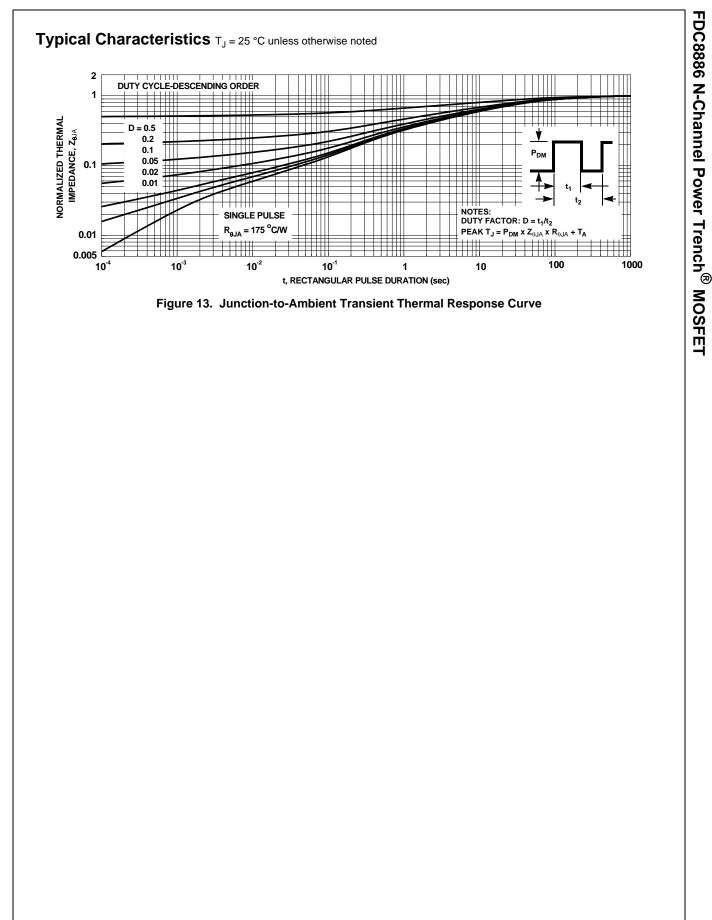
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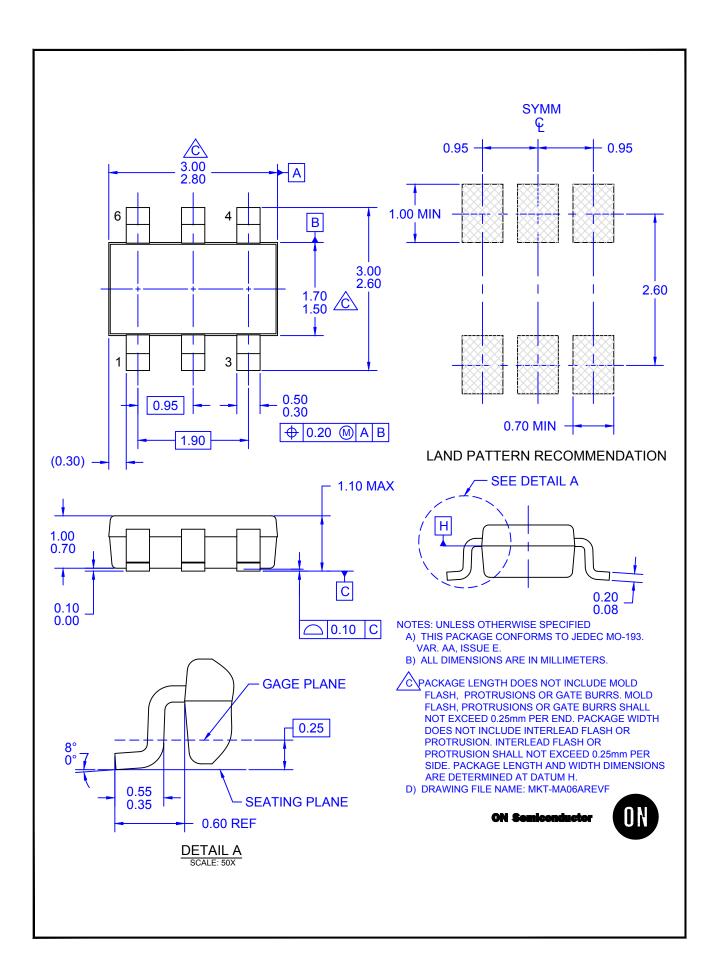


Typical Characteristics T_J = 25 °C unless otherwise noted









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